

Abstracts

On the Pressure Dependence of Microwave Crystal Rectifiers (Correspondence)

W.G. Matthei. "On the Pressure Dependence of Microwave Crystal Rectifiers (Correspondence)." 1958 Transactions on Microwave Theory and Techniques 6.1 (Jan. 1958 [T-MTT]): 112-112.

During the past couple of years, as a result of government interest, silicon microwave crystal rectifiers have not only decreased their noise figures but also have increased their resistance to adverse environments; i.e., high burnout, high temperature, excessive humidity.

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